MRF327

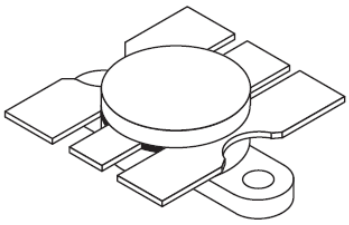
The RF Line Controlled "Q" Broadband Power Transistor 80W, 100 to 500MHz, 28V

M/A-COM Products
Released - Rev. 07.07

Designed primarily for wideband large–signal output amplifier stages in the 100 to 500 MHz frequency range.

- Guaranteed performance @ 400 MHz, 28 Vdc
  Output power = 80 W over 225 to 400 MHz Band
  Minimum gain = 7.3 dB @ 400 MHz
- Built–in matching network for broadband operation using double match technique
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Gold metallization system for high reliability applications
- Characterized for 100 =8 500 MHz

Product Image



CASE 316–01, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	33	Vdc
Collector–Base Voltage	V_{CBO}	60	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous — Peak	I_C	9.0 12	Adc
Total Device Dissipation @ T_C = 25°C (1) Derate above 25°C	P_D	250 1.43	Watts W/°C
Storage Temperature Range	T_{stg}	–65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I_C = 80 mAdc, I_B = 0)	$V_{(BR)CEO}$	33	—	—	Vdc
Collector–Emitter Breakdown Voltage (I_C = 80 mAdc, V_{BE} = 0)	$V_{(BR)CES}$	60	—	—	Vdc
Emitter–Base Breakdown Voltage (I_E = 8.0 mAdc, I_C = 0)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector–Base Breakdown Voltage (I_C = 80 mAdc, I_C = 0)	$V_{(BR)CBO}$	60	—	—	Vdc
Collector Cutoff Current (V_{CB} = 30 Vdc, I_E = 0)	I_{CBO}	—	—	5.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I_C = 4.0 Adc, V_{CE} = 5.0 Vdc)	h_{FE}	20	—	80	—

NOTE: (continued)
1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

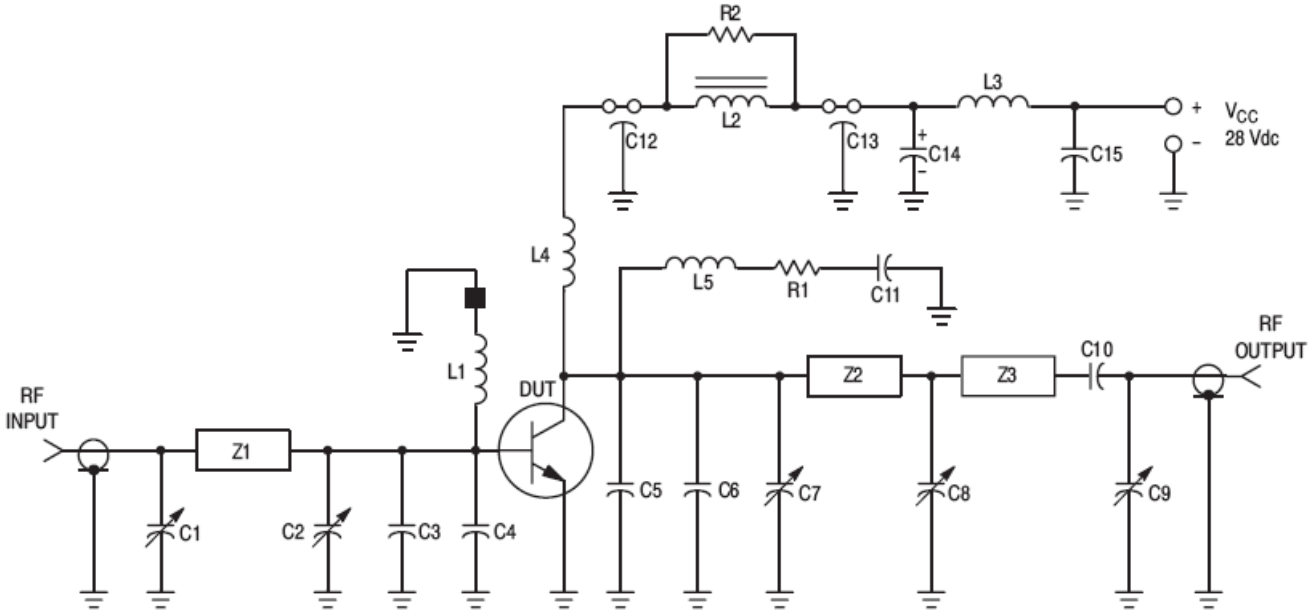
- **North America** Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- **Asia/Pacific** Tel: 81.44.844.8296 / Fax: 81.44.844.8298
  Visit www.macomtech.com for additional data sheets and product information.

DYNAMIC CHARACTERISTICS

Output Capacitance (V_{CB} = 28 Vdc, I_E = 0, f = 1.0 MHz)	C_{ob}	—	95	125	pF

ELECTRICAL CHARACTERISTICS – continued (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
FUNCTIONAL TESTS (Figure 1)					
Common–Emitter Amplifier Power Gain (V_{CC} = 28 Vdc, P_{out} = 80 W, f = 400 MHz)	G_{PE}	7.3	9.0	—	dB
Collector Efficiency (V_{CC} = 28 Vdc, P_{out} = 80 W, f = 400 MHz)	η	50	60	—	%
Load Mismatch (V_{CC} = 28 Vdc, P_{out} = 80 W, f = 400 MHz, VSWR = 30:1 All Phase Angles)	ψ	No Degradation in Output Power			



C1, C2, C7, C8, C9 — 1.0–20 pF Piston Trimmer (Johanson JMC 5501)
C3, C4 — 36 pF ATC 100 mil Chip Capacitor
C5, C6 — 43 pF ATC 100 mil Chip Capacitor
C10 — 100 pF UNELCO
C11, C15 — 0.1 µF Erie Redcap
C12, C13 — 680 pF Feedthru
C14 — 1.0 µF 50 V Tantalum
L1 — 4 Turns #22 AWG Enameled, 3/16″ ID Closewound with Ferroxcube Bead (#56–590–65/4B) on Ground End of Coil
L2 — Ferroxcube VK200–19/4B Ferrite Choke
L3 — 7 Turns #18 AWG, 11/16″ Long, Wound on a 100 kΩ 2.0 Watt Resistor
L4 — 6 Turns #20 AWG Enameled, 3/16″ ID Closewound
L5 — 4 Turns #22 AWG Enameled, 1/8″ ID Closewound
Z1 — Microstrip 0.2″ W x 1.5″ L
Z2 — Microstrip 0.17″ W x 1.16″ L
Z3 — Microstrip 0.17″ W x 0.63″ L
R1, R2 — 10 Ω 2.0 Watt
Board — Glass Teflon ε_r = 2.56, t = 0.062″
Input/Output Connectors Type N
DUT Socket Lead Frame Etched from 80–mil–Thick Copper

Figure 1. 400 MHz Test Circuit

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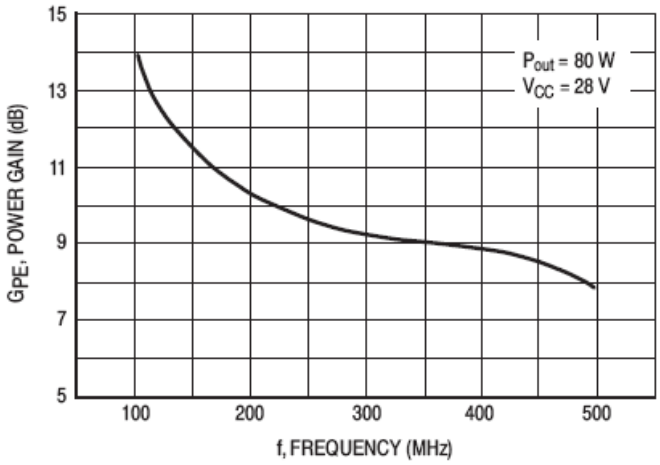

Figure 2. Power Gain versus Frequency

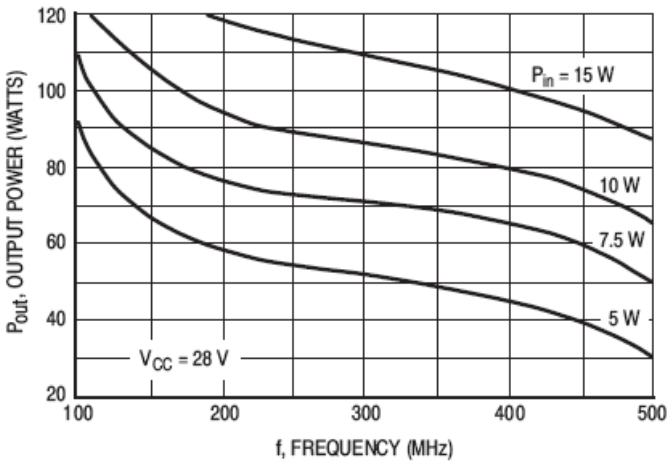

Figure 3. Output Power versus Frequency

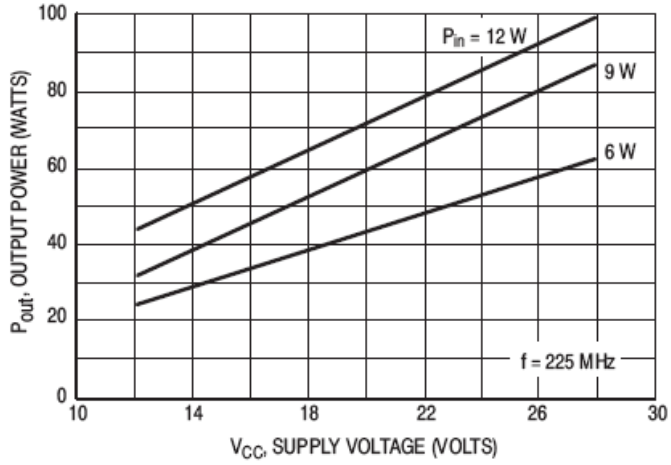

Figure 4. Output Power versus Supply Voltage

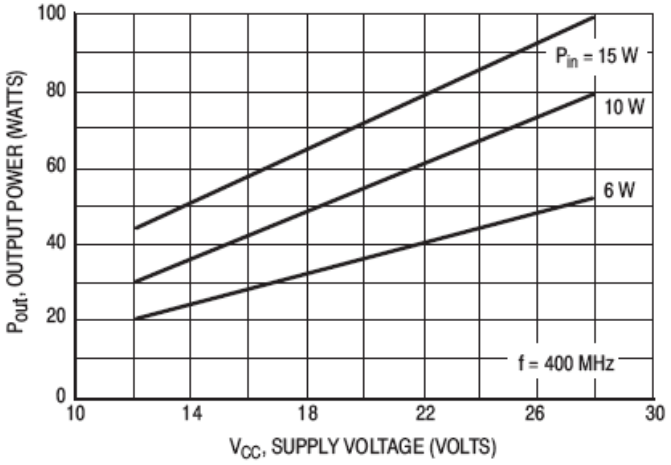

Figure 5. Output Power versus Supply Voltage

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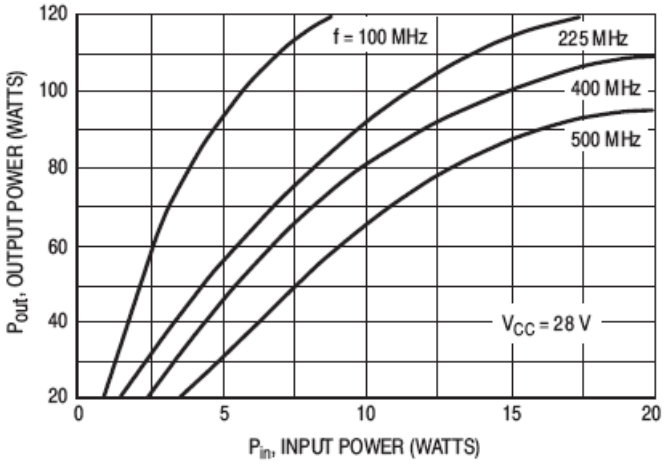
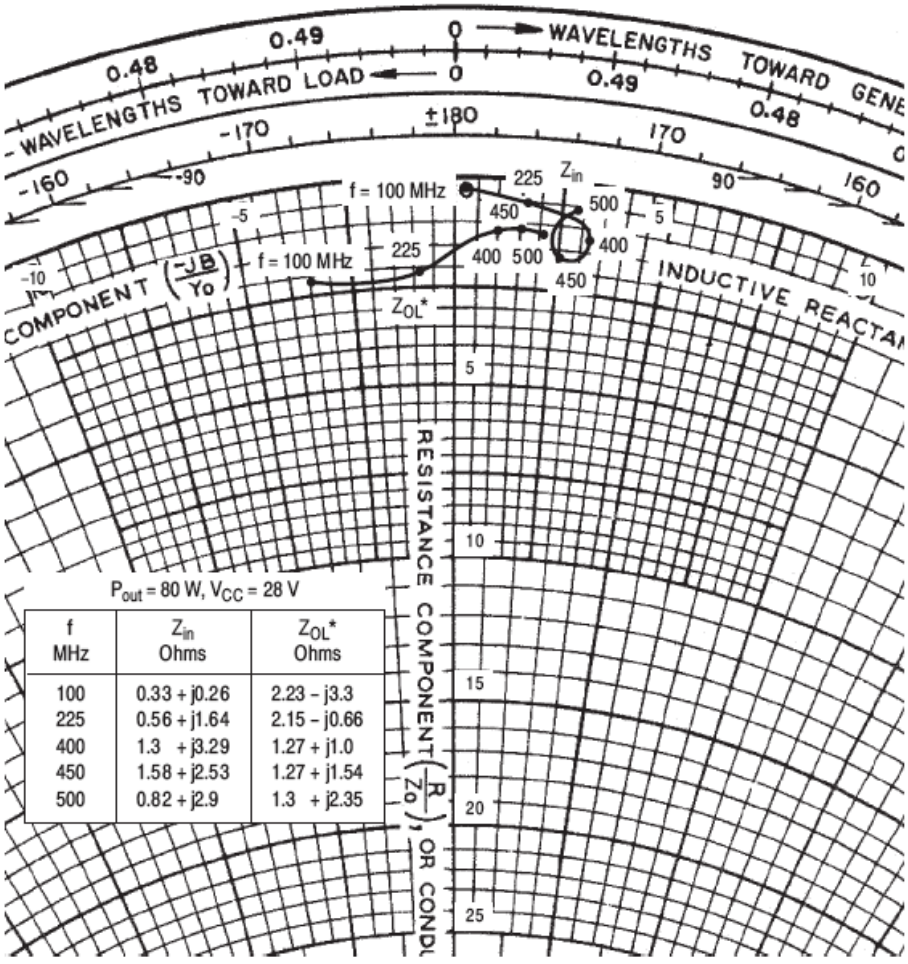


Figure 6. Output Power versus Input Power

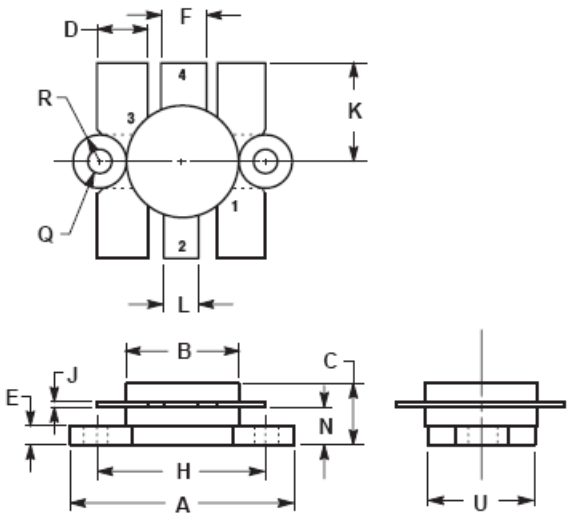


f MHz	Z_{in} Ohms	Z_{OL}* Ohms
100	0.33 + j0.26	2.23 – j3.3
225	0.56 + j1.64	2.15 – j0.66
400	1.3 + j3.29	1.27 + j1.0
450	1.58 + j2.53	1.27 + j1.54
500	0.82 + j2.9	1.3 + j2.35

Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 7. Series Equivalent Input–Output Impedance

PACKAGE DIMENSIONS



NOTES:
1. FLANGE IS ISOLATED IN ALL STYLES.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	24.38	25.14	0.960	0.990
B	12.45	12.95	0.490	0.510
C	5.97	7.62	0.235	0.300
D	5.33	5.58	0.210	0.220
E	2.16	3.04	0.085	0.120
F	5.08	5.33	0.200	0.210
H	18.29	18.54	0.720	0.730
J	0.10	0.15	0.004	0.006
K	10.29	11.17	0.405	0.440
L	3.81	4.06	0.150	0.160
N	3.81	4.31	0.150	0.170
Q	2.92	3.30	0.115	0.130
R	3.05	3.30	0.120	0.130
U	11.94	12.57	0.470	0.495

STYLE 1:
PIN 1. EMITTER
2. COLLECTOR
3. EMITTER
4. BASE

CASE 316–01
ISSUE D

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